Low Voltage Comparators

The NCS2200 Series is an industry first sub-one volt, low power comparator family. These devices consume only 10 μA of supply current. They are guaranteed to operate at a low voltage of 0.85 V which allows them to be used in systems that require less than 1.0 V and are fully operational up to 6.0 V which makes them convenient for use in both 3.0 V and 5.0 V systems. Additional features include no output phase inversion with overdriven inputs, internal hysteresis, which allows for clean output switching, and rail-to-rail input and output performance. The NCS2200 Series is available in the tiny SOT-23-5 package. There are four options featuring two industry standard pinouts. Additionally, the NCS2200 and NCS2202 are available in the SC70-5 package. The NCS2200 is also available in the tiny DFN 2x2.2 package. The NCS2200A is available in UDFN 1.2x1.0 package. (Table 1)

Features

- Operating Voltage of 0.85 V to 6.0 V
- Rail-to-Rail Input/Output Performance
- Low Supply Current of 10 μA
- No Phase Inversion with Overdriven Input Signals
- Glitchless Transitioning in or out of Tri-State Mode
- Complementary or Open Drain Output Configuration
- Internal Hysteresis
- Propagation Delay of 1.1 μs
- NCV Prefix for Automotive and Other Applications Requiring Site and Change Controls

1

• These Devices are Pb-Free and are RoHS Compliant

Typical Applications

- Single Cell NiCd/NiMH Battery Powered Applications
- Cellular Telephones
- Alarm and Security Systems
- Personal Digital Assistants



ON Semiconductor®

http://onsemi.com



SOT-23-5 (TSOP-5) SN SUFFIX CASE 483



DFN 2x2.2 SQL SUFFIX CASE 488



SC70-5 SQ SUFFIX CASE 419A



UDFN 1.2x1.0 MU SUFFIX CASE 517AA

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 12 of this data sheet.

DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 13 of this data sheet.

Table 1. Comparator Selector Guide

Output Type	Device	Package	Pinout Style
Complementary	NCS2200SN1T1G	SOT-23-5	1
Complementary	NCS2200SN2T1G	SOT-23-5	2
Complementary	NCV2200SN1T1G	SOT-23-5	1
Complementary	NCV2200SN2T1G	SOT-23-5	2
Complementary	NCS2200SQ2T2G	SC70-5	2
Complementary	NCV2200SQ2T2G	SC70-5	2
Open Drain	NCS2202SN1T1G	SOT-23-5	1
Open Drain	NCS2202SQ1T2G	SC70-5	1
Open Drain	NCS2202SN2T1G	SOT-23-5	2
Open Drain	NCS2202SQ2T2G	SC70-5	2
Complementary	NCS2200SQLT1G	DFN, 2x2.2	N/A
Complementary	NCS2200AMUT1G	UDFN, 1.2x1.0	N/A

PIN CONNECTIONS

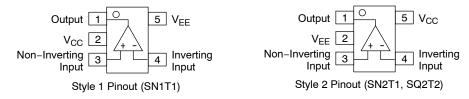


Figure 1. SOT-23-5 (NCS2200, NCS2202), SC70-5 (NCS2200, NCS2202)

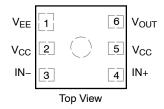


Figure 2. DFN 2x2.2 (NCS2200) UDFN 1.2x1.0 (NCS2200A)

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Supply Voltage Range (V _{CC} to V _{EE})	Vs	6.0	V
Non-inverting/Inverting Input to V _{EE}	-	-0.2 to (V _{CC} + 0.2)	V
Operating Junction Temperature	TJ	150	°C
Operating Ambient Temperature Range NCS2200, NCS2202, NCS2200A NCV2200	T _A	-40 to +105 -40 to +125	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C
Output Short Circuit Duration Time (Note 1)	t _S	Indefinite	S
ESD Tolerance (Note 2) NCS2200 Human Body Model Machine Model NCS2202 Human Body Model Machine Model NCS2200A Human Body Model Machine Model Machine Model Machine Model	-	2000 200 1000 200 1900 200	V
Thermal Resistance, Junction-to-Ambient TSOP-5 DFN (Note 3) SC70-5 UDFN	$R_{ hetaJA}$	238 215 283 350	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. The maximum package power dissipation limit must not be exceeded. $P_D = \frac{T_{J(max)} - T_{A}}{R_{\theta JA}}$ 2. ESD data available upon request.

$$P_D = \frac{T_{J(max)} - T_{A}}{Re_{JA}}$$

- 3. For more information, refer to application note, AND8080/D.

ELECTRICAL CHARACTERISTICS (For all values $V_{CC} = 0.85 \text{ V}$ to 6.0 V, $V_{EE} = 0 \text{ V}$, $T_A = 25 ^{\circ}\text{C}$, unless otherwise noted.) (Note 4)

			ICS2200 Serie	S	
Characteristics	Symbol		Min Typ		Unit
Input Hysteresis T _A = 25°C	V _{HYS}	2.0	8.0	20	mV
Input Offset Voltage $V_{CC} = 0.85 \text{ V}$ $T_A = 25^{\circ}\text{C}$	V _{IO}	-10	0.5	+10	mV
$T_A = T_{Low}$ to T_{High} (Note 5) $V_{CC} = 3.0 \text{ V}$ $T_A = 25^{\circ}\text{C}$ $T_A = T_{Low}$ to T_{High}		-12 -6.0 -8.0	- 0.5 -	+12 +6.0 +8.0	
$V_{CC} = 6.0 \text{ V}$ $T_A = 25^{\circ}\text{C}$ $T_A = T_{Low} \text{ to } T_{High}$		-5.0 -7.0	0.5 -	+5.0 +7.0	
Common Mode Voltage Range	V _{CM}	-	V _{EE} to V _{CC}	-	V
Output Leakage Current (NCS2202) V _{CC} = 6.0 V	I _{LEAK}	-	3.3	-	nA
Output Short-Circuit Sourcing or Sinking (Vout = GND)	I _{SC}	-	70	-	mA
Common Mode Rejection Ratio V _{CM} = V _{CC}	CMRR	53	65	-	dB
Input Bias Current	I _{IB}	-	1.0	-	pА
Power Supply Rejection Ratio $\Delta V_S = 2.575 \text{ V}$	PSRR	45	55	-	dB
Supply Current V _{CC} = 0.85 V	I _{CC}				μΑ
$T_A = 25$ °C $T_A = T_{Low}$ to T_{High} (Note 5) $V_{CC} = 3.0 \text{ V}$		_	10 -	15 17	
$T_A = 25$ °C $T_A = T_{Low}$ to T_{High} $V_{CC} = 6.0$ V		-	10 -	15 17	
$T_A = 25^{\circ}C$ $T_A = T_{Low}$ to T_{High}		-	10 -	15 17	
Output Voltage High (NCS2200) $V_{CC} = 0.85 \text{ V, } I_{source} = 0.5 \text{ mA}$ $T_A = 25^{\circ}\text{C}$ $T_A = T_{Low} \text{ to } T_{High} \text{ (Note 5)}$ $V_{CC} = 3.0 \text{ V, } I_{source} = 3.0 \text{ mA}$	V _{ОН}	V _{CC} - 0.2 V _{CC} - 0.225	V _{CC} - 0.10	-	٧
$T_A = 25^{\circ}C$ $T_A = T_{Low}$ to T_{High} $V_{CC} = 6.0 \text{ V}$, $I_{source} = 5.0 \text{ mA}$		V _{CC} – 0.25	V _{CC} – 0.12 –	-	
$T_A = 25$ °C $T_A = T_{Low}$ to T_{High}		V _{CC} - 0.2 V _{CC} - 0.25	V _{CC} – 0.12 –	-	
Output Voltage Low $V_{CC} = 0.85 \text{ V, } I_{sink} = 0.5 \text{ mA}$ $T_{A} = 25^{\circ}\text{C}$ $T_{A} = T_{Low} \text{ to } T_{High} \text{ (Note 5)}$	V _{OL}	-	V _{EE} + 0.10	V _{EE} + 0.2 V _{EE} + 0.225	V
V_{CC} = 3.0 V, I_{sink} = 3.0 mA T_A = 25°C T_A = T_{Low} to T_{High} V_{CC} = 6.0 V, I_{sink} = 5.0 mA		-	V _{EE} + 0.12 -	V _{EE} + 0.2 V _{EE} + 0.25	
$T_A = 25^{\circ}$ C $T_A = T_{Low}$ to T_{High}		-	V _{EE} + 0.12 -	V _{EE} + 0.2 V _{EE} + 0.25	
Propagation Delay 20 mV Overdrive, $C_L = 15 \text{ pF}$	t _{PHL} t _{PLH}	- -	0.7 1.1	-	μs
Output Fall Time V _{CC} = 6.0 V, C _L = 50 pF	t _{FALL}	-	20	-	ns
Output Rise Time V _{CC} = 6.0 V, C _L = 50 pF	t _{RISE}	-	16	-	ns
Powerup Time	t _{PU}	_	35	_	μS

^{4.} The limits over the extended temperature range are guaranteed by design only.
5. NCS2200: T_{Low} = -40°C, T_{High} = +105°C; NCV2200: T_{Low} = -40°C, T_{High} = +125°C

ELECTRICAL CHARACTERISTICS (For all values $V_{CC} = 0.85 \text{ V}$ to 6.0 V, $V_{EE} = 0 \text{ V}$, $T_A = 25 ^{\circ}\text{C}$, unless otherwise noted.) (Note 6)

		NCS2200A			
Characteristics	Symbol	Min	Тур	Max	Unit
Input Hysteresis T _A = 25°C	V _{HYS}	2.0	4.5	20	mV
Input Offset Voltage $V_{CC} = 0.85 \text{ V}$ $T_A = 25^{\circ}\text{C}$ $T_A = -40^{\circ}\text{C}$ to 105°C	V _{IO}	-10 -12	0.5 -	+10 +12	mV
$V_{CC} = 3.0 \text{ V}$ $T_A = 25^{\circ}\text{C}$ $T_A = -40^{\circ}\text{C}$ to 105°C $V_{CC} = 6.0 \text{ V}$ $T_A = 25^{\circ}\text{C}$		-6.0 -8.0 -5.0	0.5 - 0.5	+6.0 +8.0 +5.0	
$T_A = -40^{\circ}\text{C to } 105^{\circ}\text{C}$		-7.0	-	+7.0	
Common Mode Voltage Range	V _{CM}	-	V _{EE} to V _{CC}	-	V
Output Short-Circuit Sourcing or Sinking (Vout = GND)	I _{SC}	-	60	-	mA
Common Mode Rejection Ratio V _{CM} = V _{CC}	CMRR	53	70	-	dB
Input Bias Current	I _{IB}	-	1.0	-	pА
Power Supply Rejection Ratio $\Delta V_S = 2.575 \text{ V}$	PSRR	45	80	-	dB
Supply Current $V_{CC} = 0.85 \text{ V}$ $T_{A} = 25^{\circ}\text{C}$ $T_{A} = -40^{\circ}\text{C to } 105^{\circ}\text{C}$	I _{CC}	-	7.5 -	15 17	μΑ
$V_{CC} = 3.0 \text{ V}$ $T_A = 25^{\circ}\text{C}$ $T_A = -40^{\circ}\text{C} \text{ to } 105^{\circ}\text{C}$ $V_{CC} = 6.0 \text{ V}$		-	8.0 -	15 17	
T _A = 25°C T _A = -40°C to 105°C		-	9.0 -	15 17	
Output Voltage High $ \begin{array}{l} V_{CC}=0.85 \text{ V, } I_{source}=0.5 \text{ mA} \\ T_{A}=25^{\circ}\text{C} \\ T_{A}=-40^{\circ}\text{C to } 105^{\circ}\text{C} \\ V_{CC}=3.0 \text{ V, } I_{source}=3.0 \text{ mA} \end{array} $	V _{OH}	V _{CC} - 0.25 V _{CC} - 0.275	V _{CC} - 0.10	-	V
$T_A = 25$ °C $T_A = -40$ °C to 105°C		V _{CC} - 0.3 V _{CC} - 0.35	V _{CC} – 0.12 –	-	
$V_{CC} = 6.0 \text{ V}, I_{source} = 5.0 \text{ mA}$ $T_A = 25^{\circ}\text{C}$ $T_A = -40^{\circ}\text{C to } 105^{\circ}\text{C}$		V _{CC} - 0.3 V _{CC} - 0.35	V _{CC} - 0.12 -	-	
Output Voltage Low $V_{CC} = 0.85 \text{ V, } I_{sink} = 0.5 \text{ mA}$ $T_A = 25^{\circ}\text{C}$ $T_A = -40^{\circ}\text{C}$ to 105°C	V _{OL}	-	V _{EE} + 0.10 -	V _{EE} + 0.25 V _{EE} + 0.275	V
$V_{CC} = 3.0 \text{ V}, I_{sink} = 3.0 \text{ mA}$ $T_A = 25^{\circ}\text{C}$ $T_A = -40^{\circ}\text{C to } 105^{\circ}\text{C}$		-	V _{EE} + 0.12 -	V _{EE} + 0.3 V _{EE} + 0.35	
$V_{CC} = 6.0 \text{ V}, I_{sink} = 5.0 \text{ mA}$ $T_A = 25^{\circ}\text{C}$ $T_A = -40^{\circ}\text{C} \text{ to } 105^{\circ}\text{C}$		-	V _{EE} + 0.12 -	V _{EE} + 0.3 V _{EE} + 0.35	
Propagation Delay 20 mV Overdrive, C _L = 15 pF	[†] PHL [†] PLH	- -	0.5 0.5	-	μs
Output Fall Time V _{CC} = 6.0 V, C _L = 50 pF (Note 7)	t _{FALL}	-	20	-	ns
Output Rise Time V _{CC} = 6.0 V, C _L = 50 pF (Note 7)	t _{RISE}	-	16	-	ns

^{6.} The limits over the extended temperature range are guaranteed by design only.7. Input signal: 1 kHz, squarewave signal with 10 ns edge rate.

1000

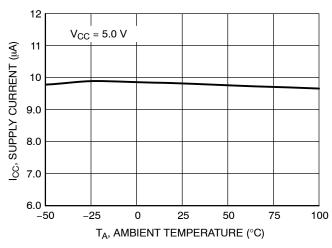
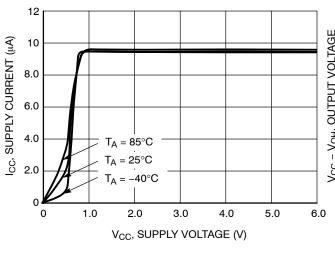


Figure 1. NCS2200 Series Supply Current versus Temperature

Figure 2. NCS2200 Series Supply Current versus Output Transition Frequency



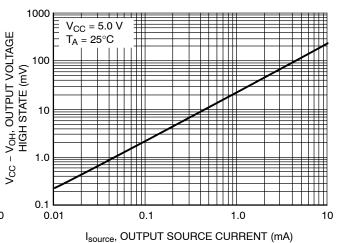
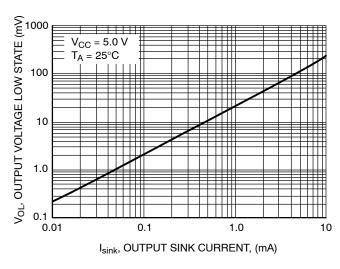


Figure 3. NCS2200 Series Supply Current versus Supply Voltage

Figure 4. NCS2200 Output Voltage High State versus Output Source Current



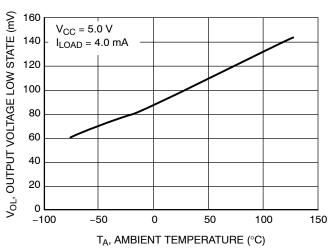


Figure 5. NCS2200 Series Output Voltage Low State versus Output Sink Current

Figure 6. NCS2200 Series Output Voltage Low State versus Temperature

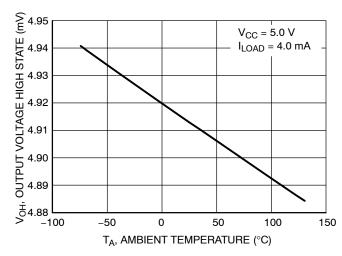


Figure 7. NCS2200 Series Output Voltage High State versus Temperature

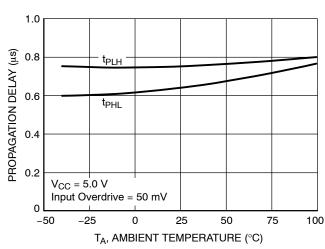


Figure 8. NCS2200 Series Propagation Delay versus Temperature

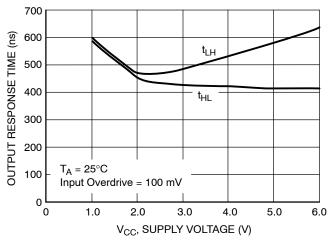


Figure 9. NCS2200 Series Output Response Time versus Supply Voltage

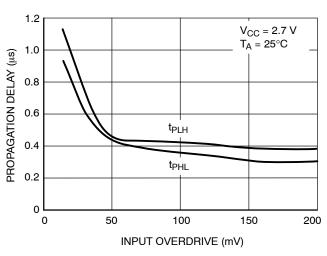


Figure 10. NCS2200 Series Propagation Delay versus Input Overdrive

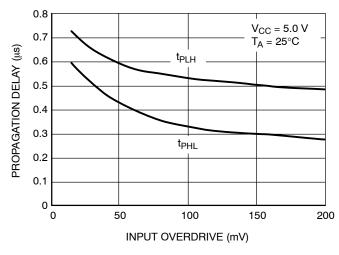


Figure 11. NCS2200 Series Propagation Delay versus Input Overdrive

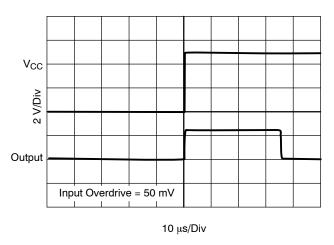


Figure 12. NCS2200 Series Powerup Delay

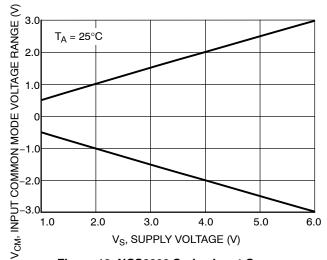


Figure 13. NCS2200 Series Input Common Mode Voltage Range versus Supply Voltage

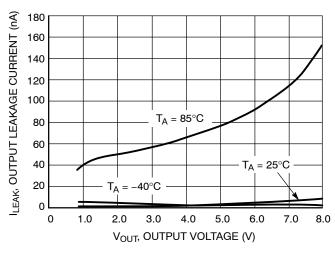


Figure 14. NCS2202 Output Leakage Current versus Output Voltage

OPERATING DESCRIPTION

The NCS2200 Series is an industry first sub-one volt, low power comparator family. This series is designed for rail-to-rail input and output performance. These devices consume only 10 μ A of supply current while achieving a typical propagation delay of 1.1 μ s at a 20 mV input overdrive. Figures 10 and 11 show propagation delay with various input overdrives. This comparator family is guaranteed to operate at a low voltage of 0.85 V up to 6.0 V. This is accomplished by the use of a modified analog CMOS process that implements depletion MOSFET devices. The common-mode input voltage range extends 0.1 V beyond the upper and lower rail without phase inversion or other adverse effects. This series is available in the SOT-23-5

package. Additionally, the NCS2200 device is available in the tiny DFN 2x2.2 package and the SC70-5 package. NCS2200A is available in UDFN package.

Output Stage

The NCS2200 has a complementary P and N Channel output stage that has capability of driving a rail-to-rail output swing with a load ranging up to 5.0 mA. It is designed such that shoot-through current is minimized while switching. This feature eliminates the need for bypass capacitors under most circumstances.

The NCS2202 has an open drain N-channel output stage that can be pulled up to $6.0\,\mathrm{V}$ (max) with an external resistor. This facilitates mixed voltage system applications.

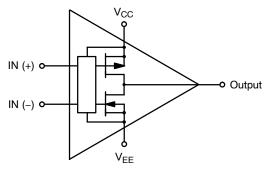


Figure 15. NCS2200SNxT1/NCS2200A Complementary Output Configuration

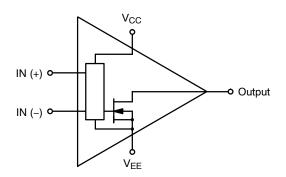
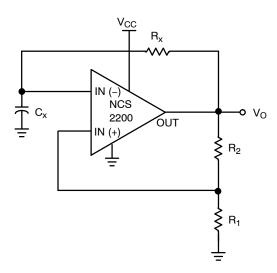


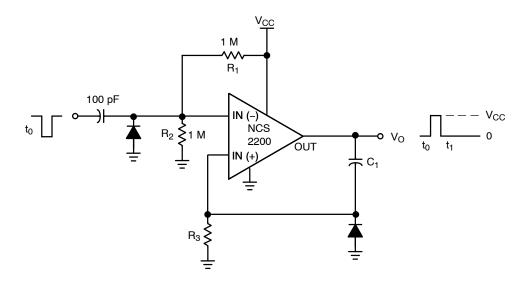
Figure 16. NCS2202SNxT1 Open Drain Output Configuration



The oscillation frequency can be programmed as follows:

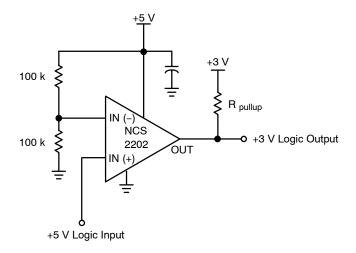
$$f = \frac{1}{T} = \frac{1}{2.2 \; R_X C_X}$$

Figure 17. Schmitt Trigger Oscillator



The resistor divider R_1 and R_2 can be used to set the magnitude of the input pulse. The pulse width is set by adjusting C_1 and R_3 .

Figure 18. One-Shot Multivibrator



This circuit converts 5 V logic to 3 V logic. Using the NCS2202/3 allows for full 5 V logic swing without creating overvoltage on the 3 V logic input.

Figure 19. Logic Level Translator

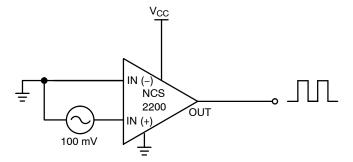


Figure 20. Zero-Crossing Detector

ORDERING INFORMATION

Device	Pinout Style	Output Type	Package	Shipping [†]
NCS2200AMUT1G	N/A	Complementary	UDFN (Pb-Free)	3000 / Tape & Reel
NCS2200SN1T1G	1	Complementary	SOT-23-5 (TSOP-5) (Pb-Free)	3000 / Tape & Reel
NCS2200SN2T1G	2	Complementary	SOT-23-5 (TSOP-5) (Pb-Free)	3000 / Tape & Reel
NCV2200SN1T1G*	1	Complementary	SOT-23-5 (TSOP-5) (Pb-Free)	3000 / Tape & Reel
NCV2200SN2T1G*	2	Complementary	SOT-23-5 (TSOP-5) (Pb-Free)	3000 / Tape & Reel
NCS2200SQ2T2G	2	Complementary	SC70-5 (Pb-Free)	3000 / Tape & Reel
NCV2200SQ2T2G*	2	Complementary	SC70-5 (Pb-Free)	3000 / Tape & Reel
NCS2200SQLT1G	N/A	Complementary	DFN, 2x2.2 (Pb-Free)	3000 / Tape & Reel
NCS2202SN1T1G	1	Open Drain	SOT-23-5 (TSOP-5) (Pb-Free)	3000 / Tape & Reel
NCS2202SQ1T2G	1	Open Drain	SC70-5 (Pb-Free)	3000 / Tape & Reel
NCS2202SN2T1G	2	Open Drain	SOT-23-5 (TSOP-5) (Pb-Free)	3000 / Tape & Reel
NCS2202SQ2T2G	2	Open Drain	SC70-5 (Pb-Free)	3000 / Tape & Reel

This device contains 93 active transistors.

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}NCV prefix indicates qualified for automotive use.

MARKING DIAGRAMS

SOT-23-5 (TSOP-5) SN SUFFIX CASE 483



x = I for NCS2200SN1T1 J for NCS2200SN2T1 M for NCS2202SN1T1 N for NCS2202SN2T1

A = Assembly Location

Y = Year W = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

DFN6 2x2.2 SQL SUFFIX CASE 488



CB = Specific Device Code

M = Date Code*

= Pb-Free Package

(Note: Microdot may be in either location)

*Date Code overbar and underbar may vary depending upon manufacturing location.

SC70-5 SQ SUFFIX CASE 419A



CBx = Specific Device Code x = A for NCS2200SQ2T2 D for NCS2202SQ1T2G E for NCS2202SQ2T2G

M = Date Code*
■ Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation, position, and underbar may vary depending upon manufacturing location.

> UDFN6 1.2x1.0 MU SUFFIX CASE 517AA



(Top View)

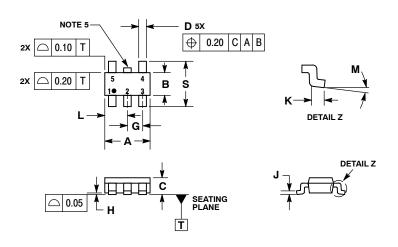
S = Specific Device Code

M = Date Code

= Pb-Free Package

PACKAGE DIMENSIONS

SOT-23-5 / TSOP-5 / SC59-5 **SN SUFFIX** PLASTIC PACKAGE CASE 483-02 **ISSUE H**



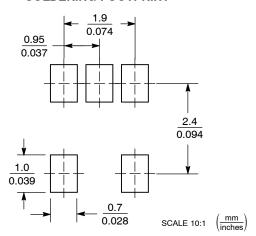
- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
- 2. CON HOLLING DIMENSION: MILLIME LEHS
 3. MAXIMUM LEAD THICKNESS INCLUDES
 LEAD FINISH THICKNESS. MINIMUM LEAD
 THICKNESS IS THE MINIMUM THICKNESS
 OF BASE MATERIAL.

 4. DIMENSIONS A AND B DO NOT INCLUDE
 MOLD FLASH, PROTRUSIONS, OR GATE
 PLUDES

 OF THE MINIMUM THICKNESS
 OF BASE MATERIAL.
- BURRS.
 5. OPTIONAL CONSTRUCTION: AN
- ADDITIONAL TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM BODY.

	MILLIMETERS		
DIM	MIN	MAX	
Α	3.00	BSC	
В	1.50	BSC	
С	0.90	0.90 1.10	
D	0.25	0.50	
G	0.95 BSC		
Н	0.01 0.10		
J	0.10	0.26	
Κ	0.20	0.60	
L	1.25	1.55	
М	0 °	10°	
S	2.50 3.00		

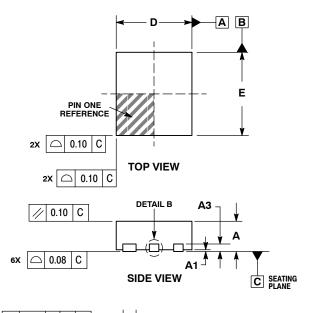
SOLDERING FOOTPRINT*

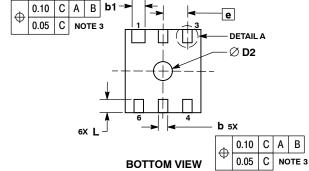


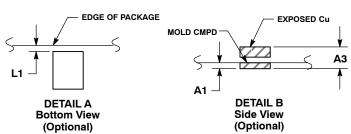
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

DFN6, 2x2.2 **SQL SUFFIX** CASE 488-03 **ISSUE G**





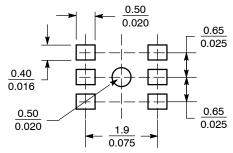


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER
- ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.

- 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30mm FROM TERMINAL.
 4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.
 5. TERMINAL & MAY HAVE MOLD COMPOUND MATERIAL ALONG SIDE EDGE.
 6. DETAILS A AND B SHOW OPTIONAL VIEWS FOR END OF TERMINAL LEAD AT EDGE OF PACKAGE.

	MILLIMETERS			
DIM	MIN	NOM	MAX	
Α	0.80	0.90	1.00	
A1	0.00	0.03	0.05	
A3		0.20 REF		
b	0.20	0.25	0.30	
b1	0.30	0.35	0.40	
D	2.00 BSC			
D2	0.40	0.50	0.60	
E	2.20 BSC			
е	0.65 BSC			
L	0.30	0.35	0.40	
L1	0.00	0.05	0.10	

SOLDERING FOOTPRINT*

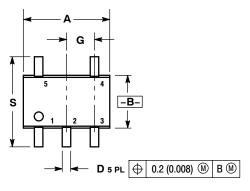


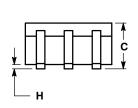
SCALE 10:1

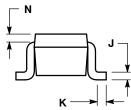
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

SC-88A (SC-70-5/SOT-353) **SQ SUFFIX** CASE 419A-02 ISSUE K



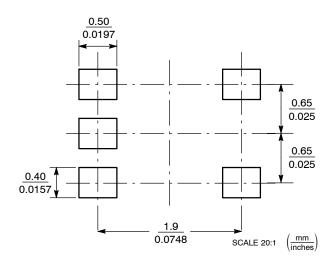




- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.
 4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.071	0.087	1.80	2.20
В	0.045	0.053	1.15	1.35
С	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026 BSC		0.65 BSC	
Н		0.004		0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20	REF
S	0.079	0.087	2.00	2.20

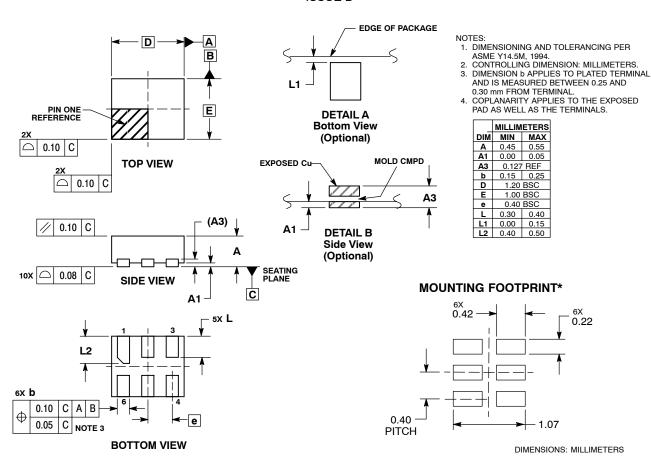
SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

UDFN6, 1.2x1.0, 0.4P CASE 517AA-01 ISSUE D



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and were registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA

Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910 Japan Customer Focus Center

Phone: 81-3-5773-3850

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative